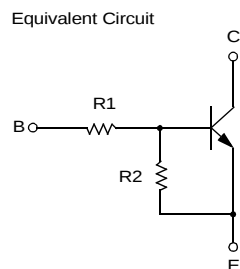
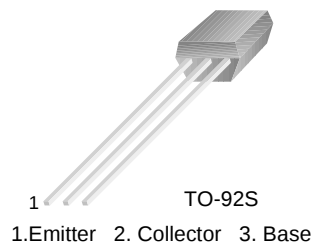


KSR1207

KSR1207

Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor ($R_1 = 22K\Omega$, $R_2 = 47K\Omega$)
- Complement to KSR2207



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	50	V
V_{CEO}	Collector-Emitter Voltage	50	V
V_{EBO}	Emitter-Base Voltage	10	V
I_C	Collector Current	100	mA
P_C	Collector Power Dissipation	300	mW
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C = 10\mu\text{A}$, $I_E = 0$	50			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 100\mu\text{A}$, $I_B = 0$	50			V
I_{CBO}	Collector Cut-off Current	$V_{CB} = 40\text{V}$, $I_E = 0$			0.1	μA
h_{FE}	DC Current Gain	$V_{CE} = 5\text{V}$, $I_C = 5\text{mA}$	68			
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 10\text{mA}$, $I_B = 0.5\text{mA}$			0.3	V
C_{ob}	Output Capacitance	$V_{CB} = 10\text{V}$, $I_E = 0$ $f = 1.0\text{MHz}$		3.7		pF
f_T	Current Gain Bandwidth Product	$V_{CE} = 5\text{V}$, $I_C = 10\text{V}$		250		MHz
$V_{I(off)}$	Input Off Voltage	$V_{CE} = 5\text{V}$, $I_C = 100\mu\text{A}$	0.4			V
$V_{I(on)}$	Input On Voltage	$V_{CE} = 0.3\text{V}$, $I_C = 2\text{mA}$			2.5	V
R_1	Input Resistor		15	22	29	$K\Omega$
R_1/R_2	Resistor Ratio		0.42	0.47	0.52	

Typical Characteristics

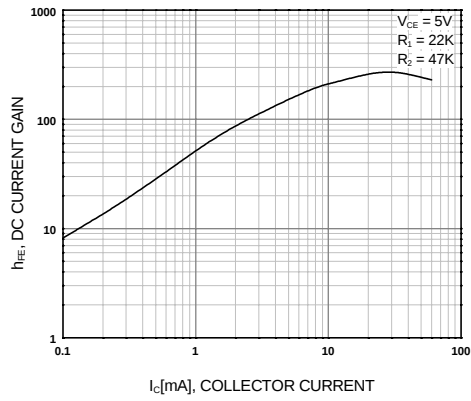


Figure 1. DC current Gain

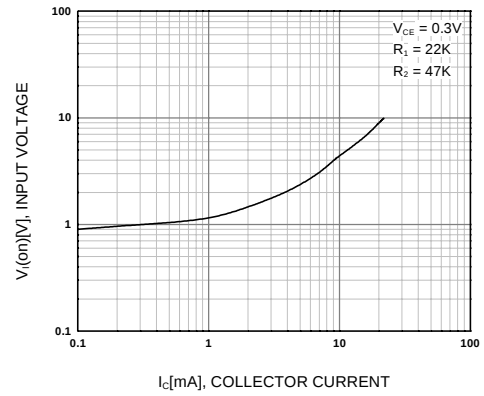


Figure 2. Input On Voltage

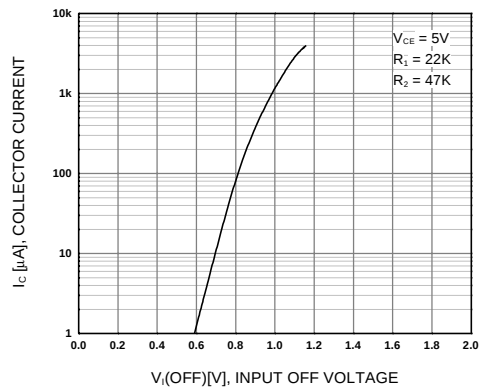


Figure 3. Input Off Voltage

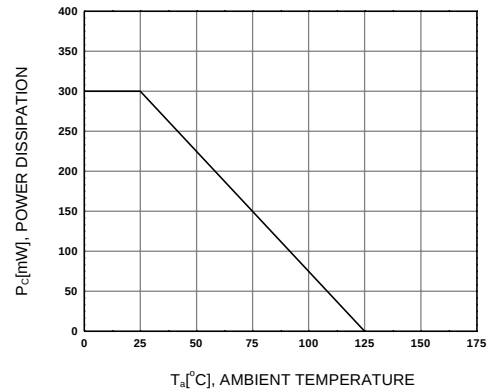
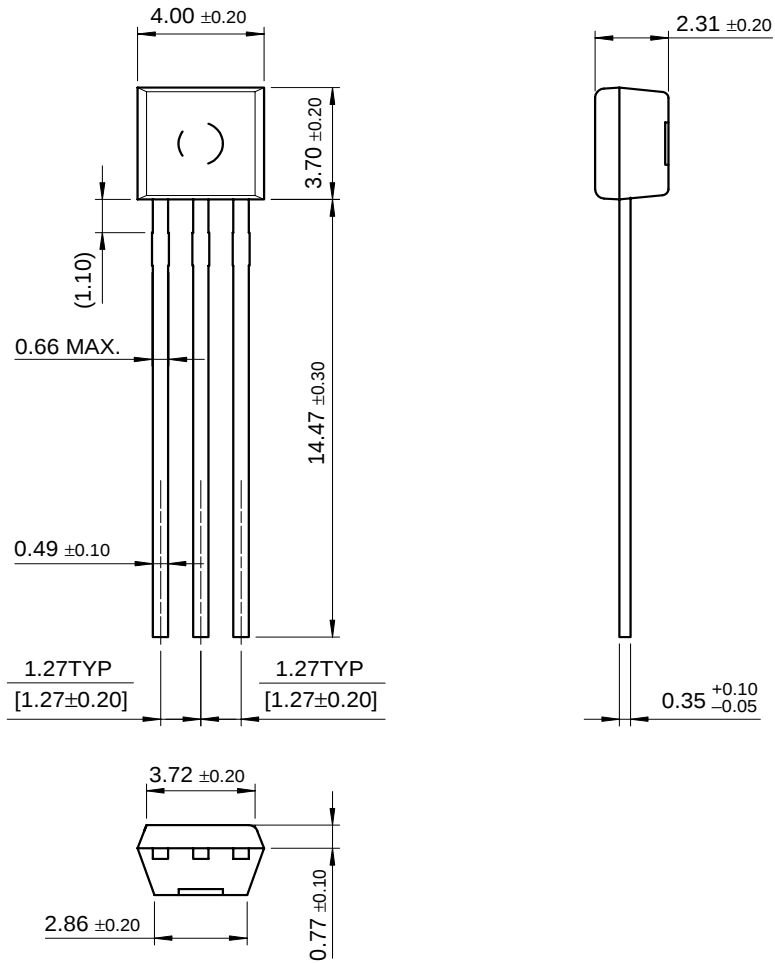


Figure 4. Power Derating

Package Dimensions

TO-92S



Dimensions in Millimeters

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